



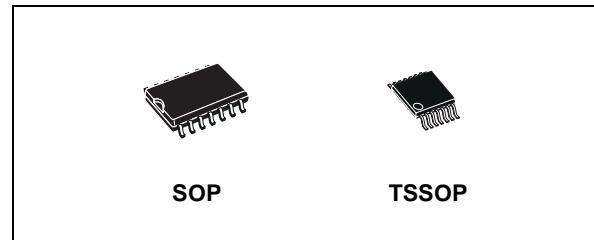
74LVX125

LOW VOLTAGE QUAD BUS BUFFERS (3-STATE) WITH 5V TOLERANT INPUTS

- HIGH SPEED: $t_{PD}=4.4\text{ns}$ (TYP.) at $V_{CC} = 3.3\text{V}$
- 5V TOLERANT INPUTS
- POWER-DOWN PROTECTION ON INPUTS
- INPUT VOLTAGE LEVEL:
 $V_{IL} = 0.8\text{V}$, $V_{IH} = 2\text{V}$ at $V_{CC} = 3\text{V}$
- LOW POWER DISSIPATION:
 $I_{CC} = 2 \mu\text{A}$ (MAX.) at $T_A=25^\circ\text{C}$
- LOW NOISE:
 $V_{OLP} = 0.3\text{V}$ (TYP.) at $V_{CC} = 3.3\text{V}$
- SYMMETRICAL OUTPUT IMPEDANCE:
 $|I_{OHI}| = I_{OL} = 4 \text{ mA}$ (MIN) at $V_{CC} = 3\text{V}$
- BALANCED PROPAGATION DELAYS:
 $t_{PLH} \approx t_{PHL}$
- OPERATING VOLTAGE RANGE:
 $V_{CC(OPR)} = 2\text{V}$ to 3.6V (1.2V Data Retention)
- PIN AND FUNCTION COMPATIBLE WITH
74 SERIES 125
- IMPROVED LATCH-UP IMMUNITY

DESCRIPTION

The 74LVX125 is a low voltage CMOS QUAD BUS BUFFERs fabricated with sub-micron silicon gate and double-layer metal wiring C²MOS technology. It is ideal for low power, battery operated and low noise 3.3V applications.



ORDER CODES

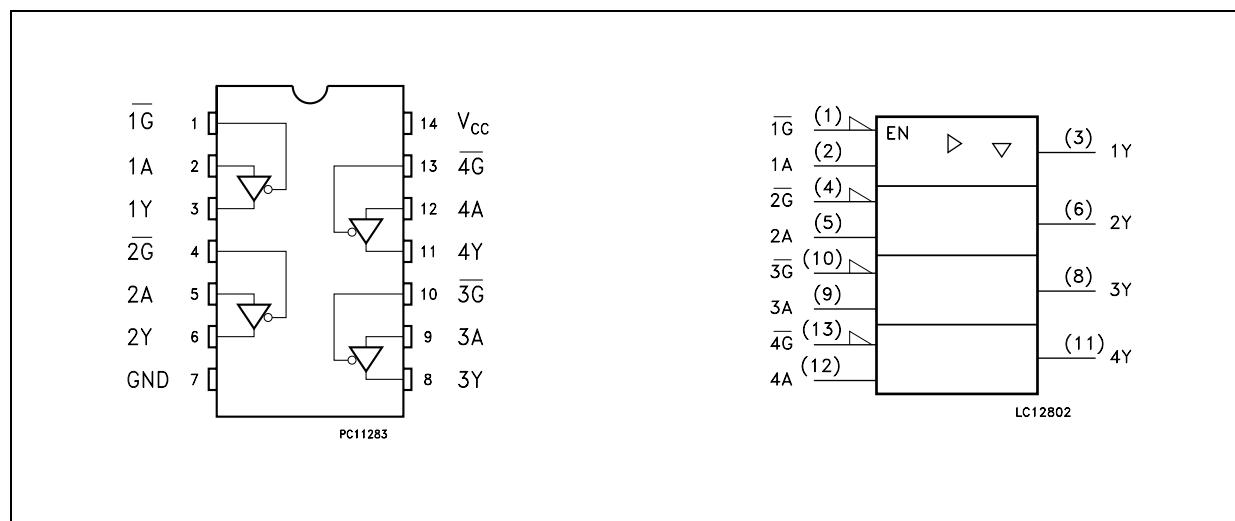
| PACKAGE | TUBE | T & R |
|---------|-----------|-------------|
| SOP | 74LVX125M | 74LVX125MTR |
| TSSOP | | 74LVX125TTR |

This device requires the 3-STATE control input \bar{G} to be set high to place the output into the high impedance state.

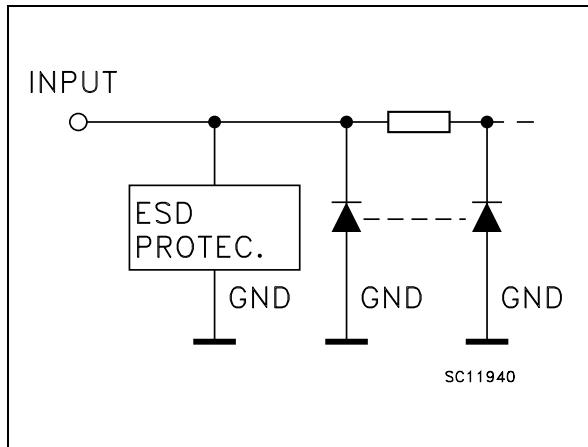
Power down protection is provided on all inputs and 0 to 7V can be accepted on inputs with no regard to the supply voltage. This device can be used to interface 5V to 3V. It combines high speed performance with the true CMOS low power consumption.

All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

PIN CONNECTION AND IEC LOGIC SYMBOLS



INPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

| PIN No | SYMBOL | NAME AND FUNCTION |
|--------------|-----------------|-------------------------|
| 1, 4, 10, 13 | 1G to 4G | Output Enable Inputs |
| 2, 5, 9, 12 | 1A to 4A | Data Inputs |
| 3, 6, 8, 11 | 1Y to 4Y | Data Outputs |
| 7 | GND | Ground (0V) |
| 14 | V _{CC} | Positive Supply Voltage |

TRUTH TABLE

| A | \bar{G} | Y |
|---|-----------|---|
| X | H | Z |
| L | L | L |
| H | L | H |

X :Don't Care

Z : High Impedance

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-------------------------------------|--------------------------------------|-------------------------------|------|
| V _{CC} | Supply Voltage | -0.5 to +7.0 | V |
| V _I | DC Input Voltage | -0.5 to +7.0 | V |
| V _O | DC Output Voltage | -0.5 to V _{CC} + 0.5 | V |
| I _{IK} | DC Input Diode Current | - 20 | mA |
| I _{OK} | DC Output Diode Current | \pm 20 | mA |
| I _O | DC Output Current | \pm 25 | mA |
| I _{CC} or I _{GND} | DC V _{CC} or Ground Current | \pm 50 | mA |
| T _{stg} | Storage Temperature | -65 to +150 | °C |
| T _L | Lead Temperature (10 sec) | 300 | °C |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Value | Unit |
|-----------------|--|----------------------|------|
| V _{CC} | Supply Voltage (note 1) | 2 to 3.6 | V |
| V _I | Input Voltage | 0 to 5.5 | V |
| V _O | Output Voltage | 0 to V _{CC} | V |
| T _{op} | Operating Temperature | -55 to 125 | °C |
| dt/dv | Input Rise and Fall Time (note 2) (V _{CC} = 3V) | 0 to 100 | ns/V |

1) Truth Table guaranteed: 1.2V to 3.6V

2) V_{IN} from 0.8V to 2.0V

DC SPECIFICATIONS

| Symbol | Parameter | Test Condition | | Value | | | | | | Unit | |
|-----------------|---------------------------------------|------------------------|--|-----------------------|------|-------|-------------|------|--------------|------|----|
| | | V _{CC} (V) | | T _A = 25°C | | | -40 to 85°C | | -55 to 125°C | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | Max. | |
| V _{IH} | High Level Input Voltage | 2.0 | | 1.5 | | | 1.5 | | 1.5 | | V |
| | | 3.0 | | 2.0 | | | 2.0 | | 2.0 | | |
| | | 3.6 | | 2.4 | | | 2.4 | | 2.4 | | |
| V _{IL} | Low Level Input Voltage | 2.0 | | | 0.5 | | 0.5 | | 0.5 | | V |
| | | 3.0 | | | 0.8 | | 0.8 | | 0.8 | | |
| | | 3.6 | | | 0.8 | | 0.8 | | 0.8 | | |
| V _{OH} | High Level Output Voltage | 2.0 | I _O =-50 μA | 1.9 | 2.0 | | 1.9 | | 1.9 | | V |
| | | 3.0 | I _O =-50 μA | 2.9 | 3.0 | | 2.9 | | 2.9 | | |
| | | 3.0 | I _O =-4 mA | 2.58 | | | 2.48 | | 2.4 | | |
| V _{OL} | Low Level Output Voltage | 2.0 | I _O =50 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | V |
| | | 3.0 | I _O =50 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | 3.0 | I _O =4 mA | | | 0.36 | | 0.44 | | 0.55 | |
| I _{OZ} | High Impedance Output Leakage Current | 3.6 | V _I = V _{IH} or V _{IL} V _O = V _{CC} or GND | | | ±0.25 | | ±2.5 | | ±5 | μA |
| I _I | Input Leakage Current | 3.6 | V _I = 5.5V or GND | | | ±0.1 | | ±1 | | ±1 | μA |
| I _{CC} | Quiescent Supply Current | 3.6 | V _I = V _{CC} or GND | | | 2 | | 20 | | 20 | μA |

DYNAMIC SWITCHING CHARACTERISTICS

| Symbol | Parameter | Test Condition | | Value | | | | | | Unit | | | | |
|------------------|--|------------------------|------------------------|-----------------------|------|------|-------------|------|--------------|------|---|--|--|--|
| | | V _{CC} (V) | | T _A = 25°C | | | -40 to 85°C | | -55 to 125°C | | | | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | Max. | | | | |
| V _{OLP} | Dynamic Low Voltage Quiet Output (note 1, 2) | 3.3 | C _L = 50 pF | | 0.3 | 0.5 | | | | | V | | | |
| | | | | -0.5 | -0.3 | | | | | | | | | |
| V _{OLV} | | | | 2.0 | | | | | | | | | | |
| | | | | | | 0.8 | | | | | | | | |
| V _{IHD} | | 3.3 | | | | | | | | | | | | |
| | | | | | | | | | | | | | | |
| V _{ILD} | | 3.3 | | | | | | | | | | | | |
| | | | | | | | | | | | | | | |

1) Worst case package.

2) Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V, (n-1) outputs switching and one output at GND.

3) Max number of data inputs (n) switching. (n-1) switching 0V to 3.3V. Inputs under test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f=1MHz.

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3\text{ns}$)

| Symbol | Parameter | Test Condition | | | Value | | | | | | Unit | |
|--------------------------|---------------------------------------|--------------------|---------------|--|--------------------------|------|------|------------------------------------|------|-------------------------------------|------|----|
| | | V_{CC} (V) | C_L (pF) | | $T_A = 25^\circ\text{C}$ | | | $-40 \text{ to } 85^\circ\text{C}$ | | $-55 \text{ to } 125^\circ\text{C}$ | | |
| | | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | |
| t_{PLH} t_{PHL} | Propagation Delay Time | 2.7 | 15 | | | 5.8 | 10.1 | 1.0 | 13.5 | 1.0 | 14.5 | ns |
| | | 2.7 | 50 | | | 8.3 | 13.6 | 1.0 | 17.0 | 1.0 | 18.0 | |
| | | 3.3 ^(*) | 15 | | | 4.4 | 6.2 | 1.0 | 8.5 | 1.0 | 9.5 | |
| | | 3.3 ^(*) | 50 | | | 6.9 | 9.7 | 1.0 | 12.0 | 1.0 | 13.0 | |
| t_{PZL} t_{PZH} | Output Enable Time | 2.7 | 15 | | | 5.3 | 9.3 | 1.0 | 12.5 | 1.0 | 13.5 | ns |
| | | 2.7 | 50 | | | 7.8 | 12.8 | 1.0 | 16.0 | 1.0 | 17.0 | |
| | | 3.3 ^(*) | 15 | | | 4.0 | 5.6 | 1.0 | 7.5 | 1.0 | 8.5 | |
| | | 3.3 ^(*) | 50 | | | 6.5 | 9.1 | 1.0 | 11.0 | 1.0 | 12.0 | |
| t_{PLZ} t_{PHZ} | Output Disable Time | 2.7 | 50 | | | 10.0 | 15.7 | 1.0 | 19.0 | 1.0 | 20.0 | ns |
| | | 3.3 ^(*) | 50 | | | 8.3 | 11.2 | 1.0 | 13.0 | 1.0 | 14.0 | |
| t_{OSLH} t_{OSHL} | Output to Output Skew Time (note 1,2) | 2.7 | 50 | | | 0.5 | 1.0 | | 1.5 | | 1.5 | ns |
| | | 3.3 ^(*) | 50 | | | 0.5 | 1.0 | | 1.5 | | 1.5 | |

1) Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs of the same device switching in the same direction, either HIGH or LOW

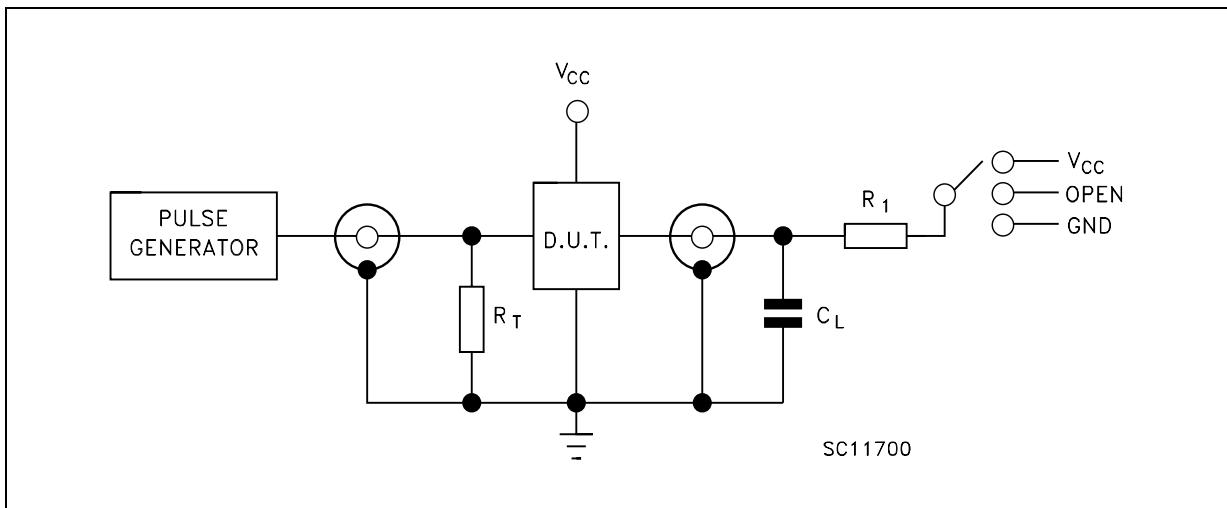
2) Parameter guaranteed by design

(*) Voltage range is $3.3\text{V} \pm 0.3\text{V}$

CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Test Condition | | | Value | | | | | | Unit | |
|-----------|--|-----------------|--|--|--------------------------|------|------|------------------------------------|------|-------------------------------------|------|----|
| | | V_{CC} (V) | | | $T_A = 25^\circ\text{C}$ | | | $-40 \text{ to } 85^\circ\text{C}$ | | $-55 \text{ to } 125^\circ\text{C}$ | | |
| | | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | |
| C_{IN} | Input Capacitance | 3.3 | | | | 4 | 10 | | 10 | | 10 | pF |
| C_{OUT} | Output Capacitance | 3.3 | | | | 6 | | | | | | pF |
| C_{PD} | Power Dissipation Capacitance (note 1) | 3.3 | | | | 14 | | | | | | pF |

1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(\text{opr})} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$ (per circuit)

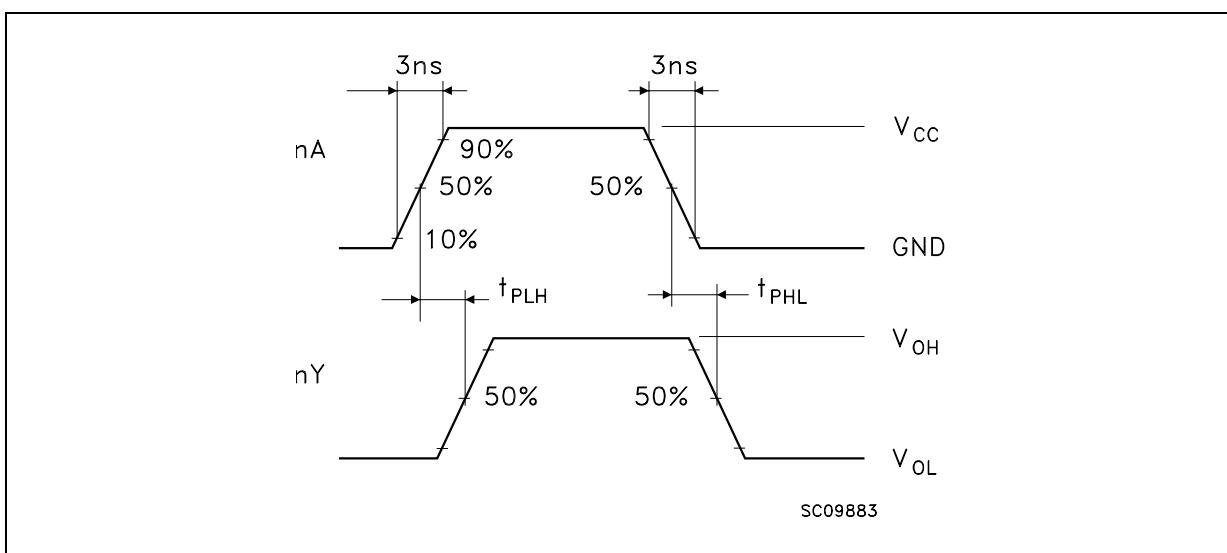
TEST CIRCUIT

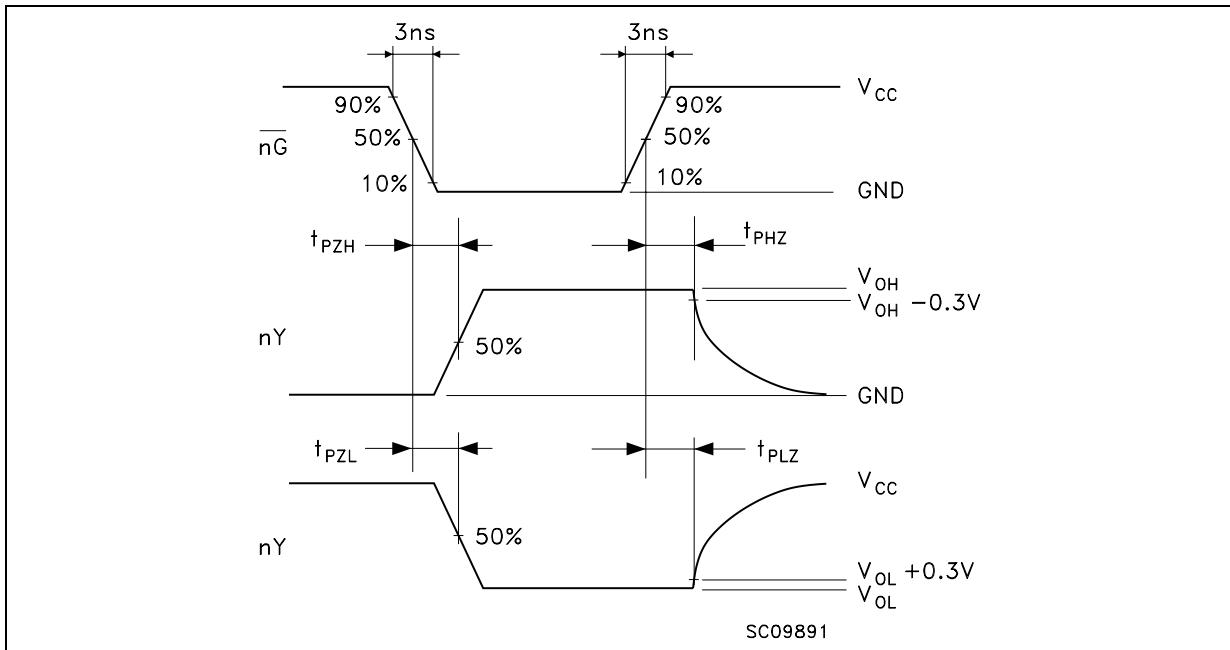
| TEST | SWITCH |
|--------------------|----------|
| t_{PLH}, t_{PHL} | Open |
| t_{PZL}, t_{PLZ} | V_{CC} |
| t_{PZH}, t_{PHZ} | GND |

$C_L = 15/50\text{pF}$ or equivalent (includes jig and probe capacitance)

$R_L = R_1 = 1\text{K}\Omega$ or equivalent

$R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

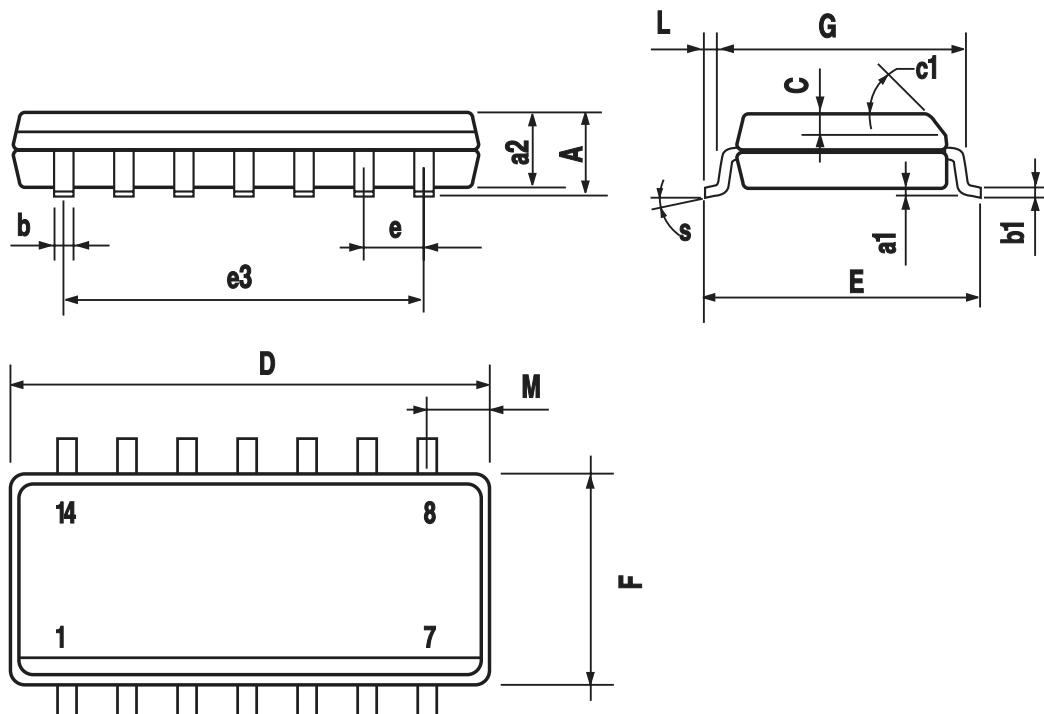
WAVEFORM 1 : PROPAGATION DELAYS (f=1MHz; 50% duty cycle)

WAVEFORM 2 : OUTPUT ENABLE AND DISABLE TIME (f=1MHz; 50% duty cycle)

SC09891

SO-14 MECHANICAL DATA

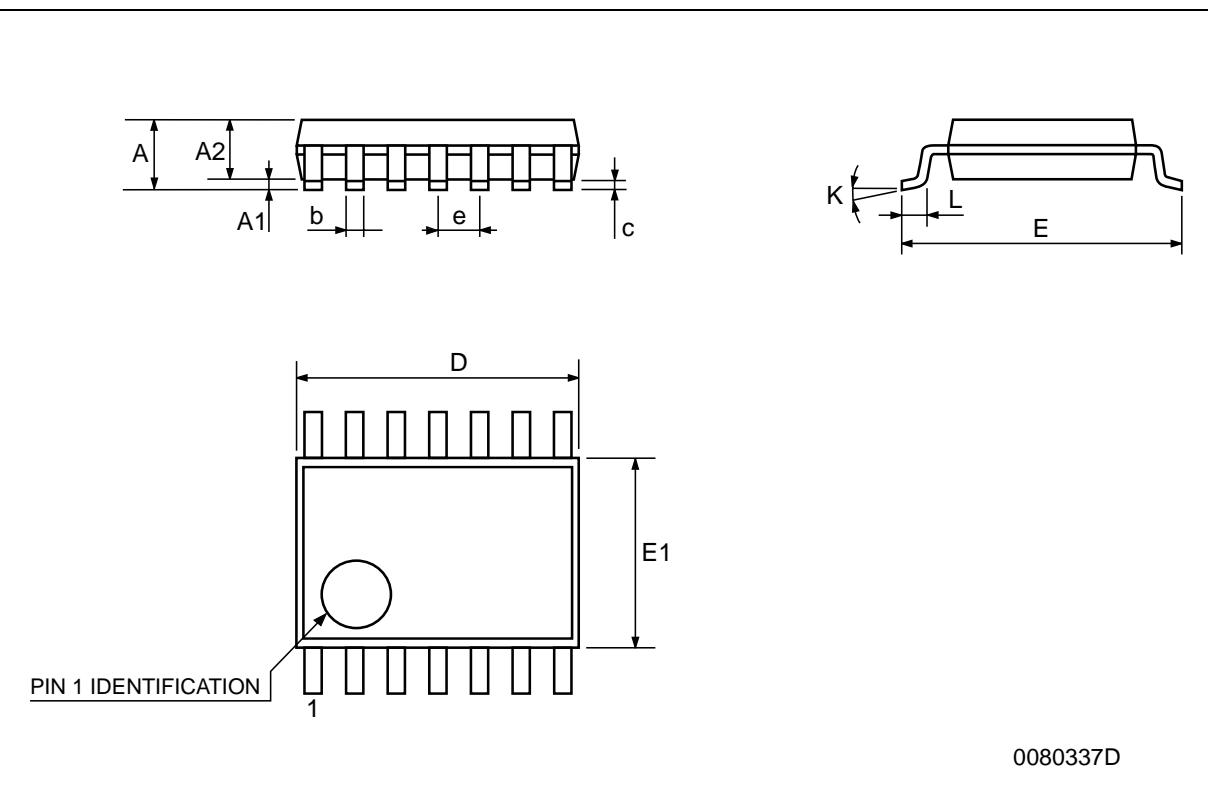
| DIM. | mm. | | | inch | | |
|------|------------|------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 1.75 | | | 0.068 |
| a1 | 0.1 | | 0.2 | 0.003 | | 0.007 |
| a2 | | | 1.65 | | | 0.064 |
| b | 0.35 | | 0.46 | 0.013 | | 0.018 |
| b1 | 0.19 | | 0.25 | 0.007 | | 0.010 |
| C | | 0.5 | | | 0.019 | |
| c1 | 45° (typ.) | | | | | |
| D | 8.55 | | 8.75 | 0.336 | | 0.344 |
| E | 5.8 | | 6.2 | 0.228 | | 0.244 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 7.62 | | | 0.300 | |
| F | 3.8 | | 4.0 | 0.149 | | 0.157 |
| G | 4.6 | | 5.3 | 0.181 | | 0.208 |
| L | 0.5 | | 1.27 | 0.019 | | 0.050 |
| M | | | 0.68 | | | 0.026 |
| S | 8° (max.) | | | | | |



PO13G

TSSOP14 MECHANICAL DATA

| DIM. | mm. | | | inch | | |
|------|------|----------|------|-------|------------|--------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 1.2 | | | 0.047 |
| A1 | 0.05 | | 0.15 | 0.002 | 0.004 | 0.006 |
| A2 | 0.8 | 1 | 1.05 | 0.031 | 0.039 | 0.041 |
| b | 0.19 | | 0.30 | 0.007 | | 0.012 |
| c | 0.09 | | 0.20 | 0.004 | | 0.0089 |
| D | 4.9 | 5 | 5.1 | 0.193 | 0.197 | 0.201 |
| E | 6.2 | 6.4 | 6.6 | 0.244 | 0.252 | 0.260 |
| E1 | 4.3 | 4.4 | 4.48 | 0.169 | 0.173 | 0.176 |
| e | | 0.65 BSC | | | 0.0256 BSC | |
| K | 0° | | 8° | 0° | | 8° |
| L | 0.45 | 0.60 | 0.75 | 0.018 | 0.024 | 0.030 |



Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

© The ST logo is a registered trademark of STMicroelectronics

© 2001 STMicroelectronics - Printed in Italy - All Rights Reserved
STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - China - Finland - France - Germany - Hong Kong - India - Italy - Japan - Malaysia - Malta - Morocco
Singapore - Spain - Sweden - Switzerland - United Kingdom

© <http://www.st.com>

